2N2906 2N2906A

## 2N2907 2N2907A

## PNP SILICON TRANSISTOR



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## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N2906, 2N2907 series types are silicon PNP epitaxial planar transistors designed for small signal, general purpose switching applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL	2N2906 2N2907	2N2906A 2N2907A	UNITS
Collector-Base Voltage	VCBO	60	60	V
Collector-Emitter Voltage	$V_{CEO}$	40	60	V
Emitter-Base Voltage	$V_{EBO}$	5.0		V
Continuous Collector Current	IC	6	00	mA
Power Dissipation	$P_{D}$	4	00	mW
Power Dissipation (T <sub>C</sub> =25°C)	$P_{D}$	1.8		W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to	+200	°C
Thermal Resistance	$\Theta_{JA}$	4	38	°C/W
Thermal Resistance	$\Theta$ JC	ę	97	°C/W

**ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

LLLCTRICAL	- CHARACTERISTICS. (TA-25 C unless of	LITE WISE	Hoteu)			
		2N2906		2N2906A		
		2N2907		2N2907A		
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
ICBO	V <sub>CB</sub> =50V	-	20	-	10	nA
ICBO	V <sub>CB</sub> =50V, T <sub>A</sub> =150°C	-	20	-	10	μΑ
ICEV	$V_{CE}$ =30V, $V_{EB}$ =0.5V	-	50	-	50	nA
BVCBO	I <sub>C</sub> =10μA	60	-	60	-	V
BVCEO	I <sub>C</sub> =10mA	40	-	60	-	V
BVEBO	I <sub>E</sub> =10μA	5.0	-	5.0	-	V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA	-	0.4	-	0.4	V
VCE(SAT)	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA	-	1.6	-	1.6	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA	-	1.3	-	1.3	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA	-	2.6	-	2.6	V
fT	$V_{CE}$ =20V, $I_{C}$ =50mA, f=100MHz	200	-	200	-	MHz
C <sub>ob</sub>	$V_{CB}$ =10V, $I_E$ =0, f=1.0MHz	-	8.0	-	8.0	pF
C <sub>ib</sub>	V <sub>EB</sub> =2.0V, I <sub>C</sub> =0, f=1.0MHz	-	30	-	30	pF
t <sub>on</sub>	V <sub>CC</sub> =30V, I <sub>C</sub> =150mA, I <sub>B1</sub> =15mA	-	45	-	45	ns
<sup>t</sup> off	$V_{CC}$ =6.0V, $I_{C}$ =150mA, $I_{B1}$ = $I_{B2}$ =15mA	-	100	-	100	ns

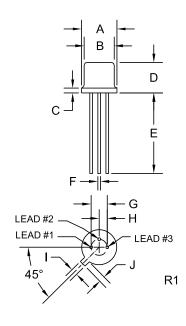
## 2N2906 2N2906A 2N2907 2N2907A





ELECTRICAL CHARACTERISTICS - Continued: (T <sub>A</sub> =25°C)		2N2906 2N2906A		2N2907 2N2907A	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =0.1mA (2N2906, 2N2907)	20	-	35	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =0.1mA (2N2906A, 2N2907A)	40	-	75	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA (2N2906, 2N2907)	25	-	50	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA (2N2906A, 2N2907A)	40	-	100	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA (2N2906, 2N2907)	35	-	75	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA (2N2906A, 2N2907A)	40	-	100	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	40	120	100	300
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA (2N2906, 2N2907)	20	-	30	-
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA (2N2906A, 2N2907A)	40	-	50	-

## **TO-18 CASE - MECHANICAL OUTLINE**



DIMENSIONS					
	INC	HES	MILLIM	ETERS	
SYMBOL	MIN	MAX	MIN	MAX	
A (DIA)	0.209	0.230	5.31	5.84	
B (DIA)	0.178	0.195	4.52	4.95	
С	-	0.030	-	0.76	
D	0.170	0.210	4.32	5.33	
E	0.500	-	12.70	-	
F (DIA)	0.016	0.019	0.41	0.48	
G (DIA)	0.100		2.54		
Н	0.050		1.27		
I	0.036	0.046	0.91	1.17	
J	0.028	0.048	0.71	1.22	
TO 10 (DEV): D1)					

TO-18 (REV: R1)

## LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R4 (30-January 2012)

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